

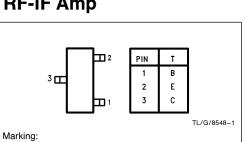
MMBTH34 Surface Mount NPN RF-IF Amp

General Description

This device was designed for common-emitter low noise amplifier and mixer applications in the 100 μA to 15 mA range to 300 MHz, and low frequency drift common-base VHF oscillator applications with high output levels for driving FET mixers.

Absolute Maximum Ratings

Collector-Base Voltage	45V				
Emitter-Base Voltage	4.0V				
Collector Current—Continuous	100 mA				
Total Device Dissipation, $T_A = 25^{\circ}C$ Derate above 25°C (Note 1)	350°C 2.8 mW/°C				
Operating Temperature Range	-55°C to +150°C				
Storage Temperature Range	-55°C to +150°C				
Lead Temperature for 10 seconds	300°C				
Note 1: Package mounted on 99.5% alumina 10 x 8 x 0.6 mm.					



MMBTH34-3K Refer to Process 47 for graphs.

Symbol	Conditions	Min	Тур	Max	Units
BV _{CBO}	$I_{C} = 100 \ \mu A$	45			V
BV _{CEO}	$I_{\rm C} = 1.0 \rm mA$	45			V
BV _{EBO}	I _E = 10 μA	4.0			V
I _{CBO}	$V_{CB} = 30V$			50	nA
ICES	$V_{CE} = 30V$			50	nA
h _{FE}	$V_{CE} = 15V, I_{C} = 7.0 \text{ mA}$	40			
h _{FE}	$V_{CE} = 2.0V, I_{C} = 20 \text{ mA}$	15			
V _{CE(s)}	$I_{\rm C} = 20$ mA, $I_{\rm B} = 2.0$ mA			0.5	V
V _{BE(on)}	$V_{CE} = 15V, I_{C} = 7.0 \text{ mA}$			0.95	V
C _{cb}	$V_{CB} = 10V$, f = 1 MHz			0.32	pF
h _{fe}	$V_{CE} = 15V, I_{C} = 15 \text{ mA}, f = 100 \text{ MHz}$	5.0			

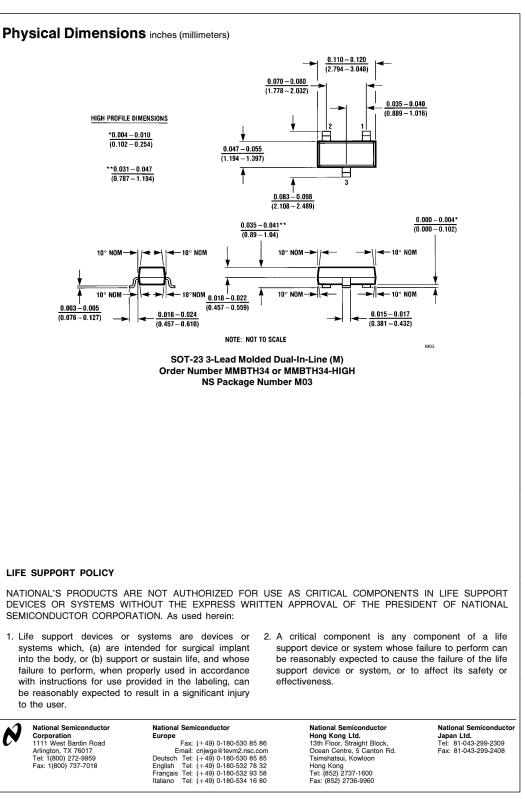
Order Number MMBTH34 or MMBTH34-HIGH See NS Package Number M03

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